

SURFACE MOUNT TRANSIENT **VOLTAGE SUPPRESSORS**

DESCRIPTION

Microsemi's new Powermite UPT series transient voltage suppressors feature oxide-passivated chips, with high-temperature solder bonds for high surge capability, and negligible electrical degradation under repeated surge conditions.

In addition to its size advantages, Powermite package includes a full metallic bottom that eliminates the possibility of solder flux entrapment at assembly and a unique locking tab serving as an integral heat sink.

Innovative design makes this device fully compatible for use with automatic insertion equipment.

IMPORTANT: For the most current data, consult *MICROSEMI's* website: http://www.microsemi.com

FEATURES

- Powermite Package with standoff voltages 5 to 48 V ٠
- Both unidirectional and Bidirectional Versions . Available as "UPT" and "UPTB" respectively
- Peak Pulse Power 1000 W for 8/20 µs pulse .
- Clamping Time in pico-seconds
- Integral heat sink / locking tabs
- Full metallic bottom eliminates flux entrapment .
- Moisture classification is Level 1 with no dry pack required per IPC/JEDEC J-STD-020B
- Options for screening in accordance with MIL-PRF-19500 for JAN, JANTX, JANTXV, or JANS are available by adding MQ, MX, MV, or MSP prefixes respectively to part numbers, e.g. MXUPT15, MVUPTB28, MSPUPT10, etc.

MAXIMUM RATINGS

- Operating and Storage Temperature: -65°C to • +150°C
- Peak Pulse Power: 1000 W at 8/20 µs pulse (See Figure 1 and 2).
- Peak Pulse Power: 150 W at 10/1000 µs pulse (See Figure 2).
- Impulse Repetition Rate (duty factor): 0.01%
- Thermal resistance: 15°C/W junction to base tab or 85°C/W junction to ambient when mounted on FR4 PC board with 1 oz copper
- Steady-State Power: 2.5 Watts •
- Solder Temperatures: 260°C for 10 s (maximum)

APPLICATIONS / BENEFITS

- Protects sensitive components such as IC's, ٠ CMOS, Bipolar, BiCMOS, ECL, DTL, T²L, etc.
- Protection from switching transients & induced • RF
- Compliant to IEC61000-4-2 and IEC61000-4-4 • for ESD and EFT protection respectively
- Secondary lightning protection per IEC61000-4-5 • with 42 Ohms source impedance:
 - Class 1: UPT/UPTB5 to 17
 - Class 2: UPT/UPTB5 to 12
 - Class 3: UPT/UPTB5
- Secondary lightning protection per IEC61000-4-5 . with 12 Ohms source impedance: Class 1: UPT/UPTB5 to 8

MECHANICAL AND PACKAGING

- CASE: Void-free transfer molded thermosetting • epoxy compound meeting UL94V-0
- FINISH: Tin-Lead plated over copper and readily • solderable per MIL-STD-750, method 2026
- POLARITY: Cathode designated by TAB 1 •
- MARKING: The last three digits of part number. • e.g. UPT5 is T05, UPT12 is T12, UPT24 is T24, UPTB5 is B05, UPTB12 is B12, UPTB24 is B24, etc.
- WEIGHT: 0.016 gram (approximate) •
- See package dimension on last page •
- Tape & Reel option: Standard per EIA-481-B • 7 inch 3,000 pieces and 13 inch 12,000 pieces

UPTB5

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UPTB48 UPT48

UPT5

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UPT5 – UPT48 UPTB5 – UPTB48

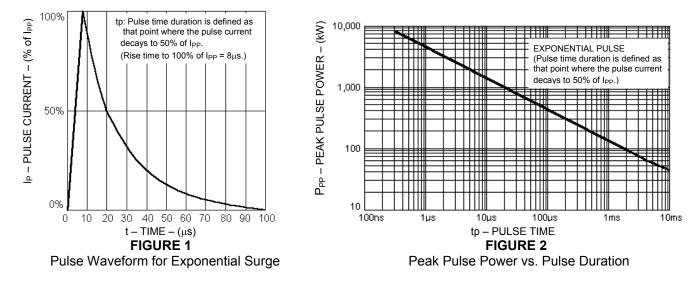
SURFACE MOUNT TRANSIENT VOLTAGE SUPPRESSORS

ELECTRICAL CHARACTERISTICS @ 25°C						
TYPE	RATED STANDOFF VOLTAGE	MINIMUM BREAKDOWN VOLTAGE	MAXIMUM STANDBY CURRENT	MAXIMUM PEAK PULSE CURRENT*	MAXIMUM CLAMPING VOLTAGE	MAXIMUM TEMP. COEFFICIENT of V _(BR)
	V _{WM}	V _(BR) @ 1 mA	I _D @ V _{₩М}	I _{PP}	Vc @ 10A	α _{v(BR)}
Bi-directional	V	V	μA	Α	V	%/°C
UPTB5	5	6.0	50	89.4	9.5	.030
UPTB8	8	9.0	2	62.1	13.7	.040
UPTB10	10	11.0	2	47.2	18.0	.045
UPTB12	12	13.8	1	40.3	21.6	.050
UPTB15	15	16.7	1	33.9	26.0	.055
UPTB17	17	19.0	1	30.8	29.2	.060
UPTB24	24	28.4	1	22.0	43.2	.070
UPTB28	28	31.0	1	19.2	47.8	.075
UPTB33	33	36.8	1	16.4	56.7	.080
UPTB48	48	54.0	1	11.2	84.3	.090
	Bi-directional UPTB5 UPTB8 UPTB10 UPTB12 UPTB15 UPTB17 UPTB24 UPTB28 UPTB33	RATED STANDOFF VOLTAGE Bi-directional V Bi-directional V UPTB5 5 UPTB8 8 UPTB10 10 UPTB15 15 UPTB15 15 UPTB17 17 UPTB24 24 UPTB33 33	RATED STANDOFF VOLTAGE MINIMUM BREAKDOWN VOLTAGE Vwm V(BR) @ 1 mA Bi-directional V V UPTB5 5 6.0 UPTB5 5 6.0 UPTB4 8 9.0 UPTB10 10 11.0 UPTB12 12 13.8 UPTB15 15 16.7 UPTB17 17 19.0 UPTB24 24 28.4 UPTB33 33 36.8	RATED STANDOFF VOLTAGE MINIMUM BREAKDOWN VOLTAGE MAXIMUM STANDBY CURRENT Wwm V VULTAGE STANDBY CURRENT Bi-directional V V(BR) @ 1 mA ID @ Vwm Bi-directional V V µA UPTB5 5 6.0 50 UPTB8 8 9.0 2 UPTB10 10 11.0 2 UPTB12 12 13.8 1 UPTB15 15 16.7 1 UPTB17 17 19.0 1 UPTB24 24 28.4 1 UPTB33 33 36.8 1	RATED STANDOFF VOLTAGE MINIMUM BREAKDOWN VOLTAGE MAXIMUM STANDBY CURRENT MAXIMUM PEAK PULSE CURRENT* Wwm V V PULSE Vwm V(BR) @ 1 mA ID @ Vwm IPP Bi-directional V V µA A UPTB5 5 6.0 50 89.4 UPTB8 8 9.0 2 62.1 UPTB10 10 11.0 2 47.2 UPTB12 12 13.8 1 40.3 UPTB15 15 16.7 1 33.9 UPTB24 24 28.4 1 22.0 UPTB28 28 31.0 1 19.2 UPTB33 33 36.8 1 16.4	RATED STANDOFF VOLTAGE MINIMUM BREAKDOWN VOLTAGE MAXIMUM STANDBY CURRENT MAXIMUM PEAK PULSE CURRENT* MAXIMUM CLAMPING VOLTAGE Bi-directional V V(BR) @ 1 mA ID @ V _{WM} IPP Vc @ 10A Bi-directional V V µA A V UPTB5 5 6.0 50 89.4 9.5 UPTB8 8 9.0 2 62.1 13.7 UPTB10 10 11.0 2 47.2 18.0 UPTB12 12 13.8 1 40.3 21.6 UPTB15 15 16.7 1 33.9 26.0 UPTB17 17 19.0 1 30.8 29.2 UPTB24 24 28.4 1 22.0 43.2 UPTB28 28 31.0 1 19.2 47.8 UPTB33 33 36.8 1 16.4 56.7

* See Figure 1 for I_{PP} waveform

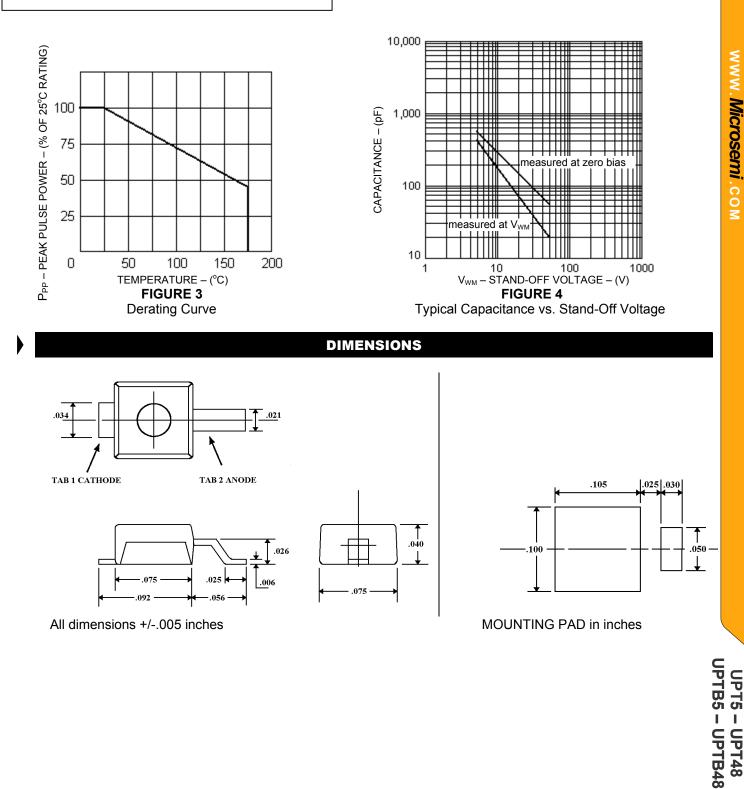
	SYMBOLS & DEFINITIONS
Symbol	Definition
V _(BR)	Breakdown Voltage: The minimum voltage the device will exhibit at a specified current.
V _{WM}	Working Peak Standoff Voltage: The maximum peak voltage that can be applied over the operating temperature range.
P _{PP}	Peak Pulse Power: The peak power that can be applied for a specified pulse width and waveform.
I _D	Standby Current: The maximum current that will flow at the specified voltage and temperature.
I _{PP}	Peak Pulse Current: The peak current that can be applied for a specified pulse width and waveform.
С	Capacitance: The capacitance in picofarads of the TVS as defined @ 0 volts at a frequency of 1 MHz.

OUTLINE AND CIRCUIT





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Page 3

UPT48